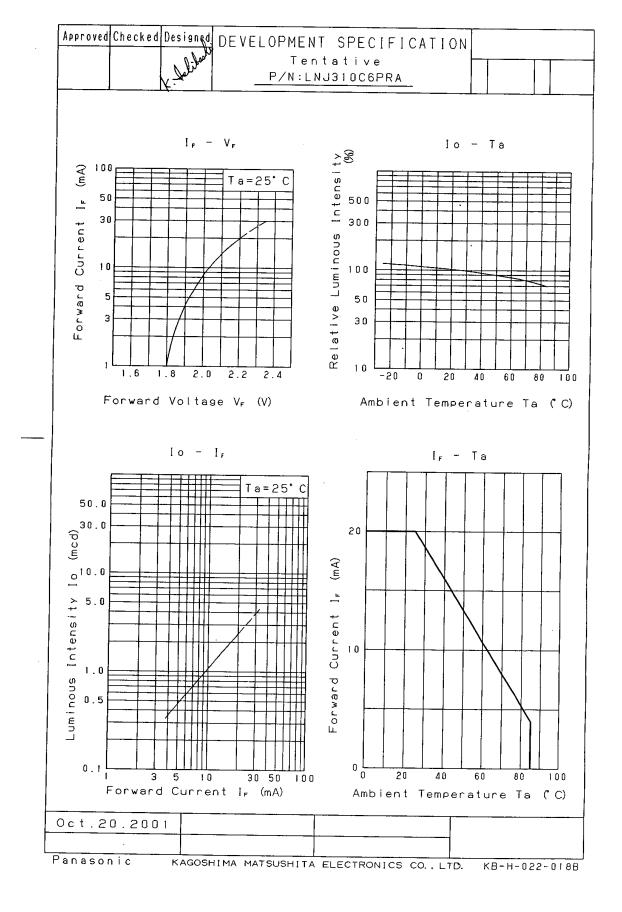
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<ul> <li>*1 · The</li> <li>Plea</li> <li>(bel</li> <li>*2 Meas</li> <li>NOTE</li> <li>★1. Term</li> <li>★2. Packa</li> <li>★3. Solde</li> </ul>	Condition ase contac ow 1 mA D surement To inal:Plate age : Clea	of I <sub>FP</sub> is t the Par C) or pul olerance ed with g ar type. litions.	s duty pasonio is ±2 old or	I <sub>F</sub> = 10%, F c local o rrent ope 20%.	10 mA Pulse width ffice if y ration and	DC 1 ms ou design	n at low	current	ε	n,
<ul> <li>*1 • The</li> <li>Plea</li> <li>(bel</li> <li>*2 Meas</li> <li>NOTE</li> <li>★1. Term</li> <li>★2. Packa</li> <li>★3. Solda</li> <li>Refer</li> <li>★4. Care</li> </ul>	Condition ase contac low 1 mA D surement To inal:Plate age : Clez ering cond r to Hand]	of I <sub>FP</sub> is t the Par C) or pul olerance ed with g ar type. litions. ing note.	s duty hasonid lse cun is ±2 cold or	I <sub>F</sub> == 10 %, F c local o rrent ope 20%.	10 mA Pulse width ffice if y ration and	DC 1 ms ou desigr have any	n at low 7 questic	ns.		n
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